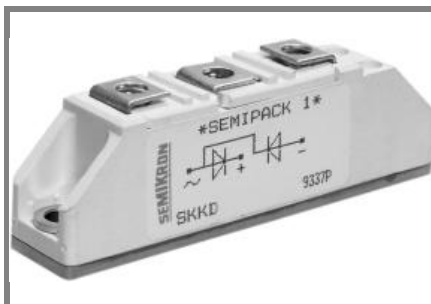


SKKD 42F, SKMD 42F, SKND 42F



SEMIPACK® 1

Fast Diode Modules

SKKD 42F

SKMD 42F

SKND 42F

Features

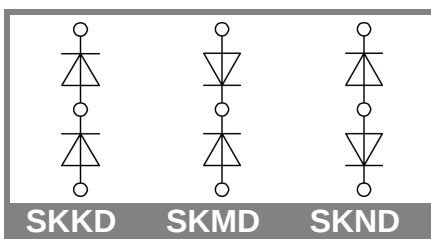
- Heat transfer through ceramic isolated metal baseplate
- Hard soldered joints for high reliability
- SKKD half bridge connection; SKMD common cathode; SKND common anode
- UL recognized, file no. E 63 532

Typical Applications

- Self-commutated inverters
- DC choppers
- AC motor speed control
- Inductive heating
- Uninterruptible power supplies
- Electronic welders
- General power switching applications

V_{RSM} V	V_{RRM} V	$I_{FRMS} = 120$ A (maximum value for continuous operation) $I_{FAV} = 42$ A (sin. 180; 50 Hz; $T_c = 85$ °C)		
1000	1000	SKKD 42F10	SKMD 42F10	SKND 42F12
1200	1200	SKKD 42F12	SKMD 42F12	SKND 42F14
1400	1400	SKKD 42F14	SKMD 42F14	SKND 42F15
1500	1500	SKKD 42F15	SKMD 42F15	SKKD 42F15

Symbol	Conditions	Values	Units
I_{FAV}	sin. 180; $T_c = 85$ (100) °C	42 (31)	A
I_{FSM}	$T_{vj} = 25$ °C; 10 ms	1200	A
	$T_{vj} = 130$ °C; 10 ms	1100	A
i^2t	$T_{vj} = 25$ °C; 8,3 ... 10 ms	7200	A²s
	$T_{vj} = 130$ °C; 8,3 ... 10 ms	6000	A²s
V_F	$T_{vj} = 25$ °C; $I_F = 150$ A	max. 1,85	V
$V_{(TO)}$	$T_{vj} = 130$ °C	1	V
r_T	$T_{vj} = 130$ °C	5	mΩ
I_{RD}	$T_{vj} = 25$ °C; $V_{RD} = V_{RRM}$	max. 0,4	mA
I_{RD}	$T_{vj} = 130$ °C; $V_{RD} = V_{RRM}$	max. 30	mA
Q_{rr}	$T_{vj} = 130$ °C; $I_F = 50$ A,	75	μC
I_{RM}	$-di/dt = 50$ A/μs, $V_R = 30$ V	70	A
t_{rr}		2140	ns
E_{rr}		1,12	mJ
$R_{th(j-c)}$	per diode / per module	0,7 / 0,35	K/W
$R_{th(c-s)}$	per diode / per module	0,2 / 0,1	K/W
T_{vj}		- 40 ... + 130	°C
T_{stg}		- 40 ... + 125	°C
V_{isol}	a. c. 50 Hz; r.m.s.; 1 s / 1 min.	3600 / 3000	V~
M_s	to heatsink	5 ± 15 %	Nm
M_t	to terminals	3 ± 15 %	Nm
a		5 * 9,81	m/s²
m	approx.	120	g
Case	SKKD	A 10	
	SKMD	A 33	
	SKND	A 37	

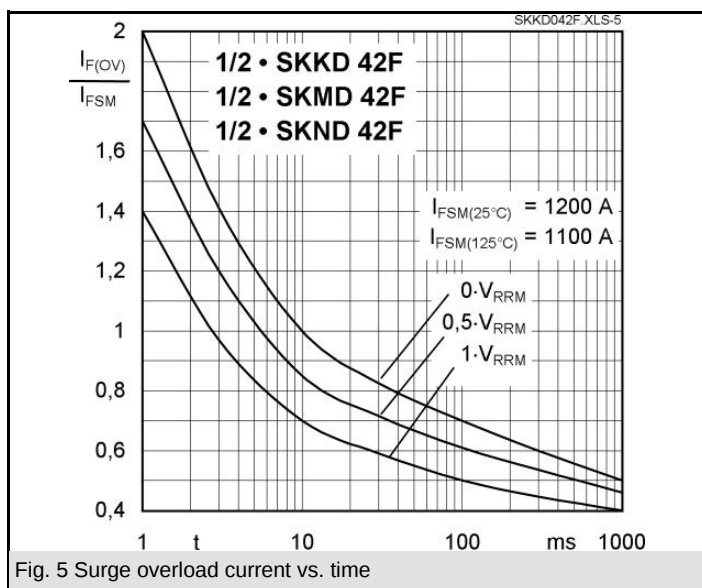
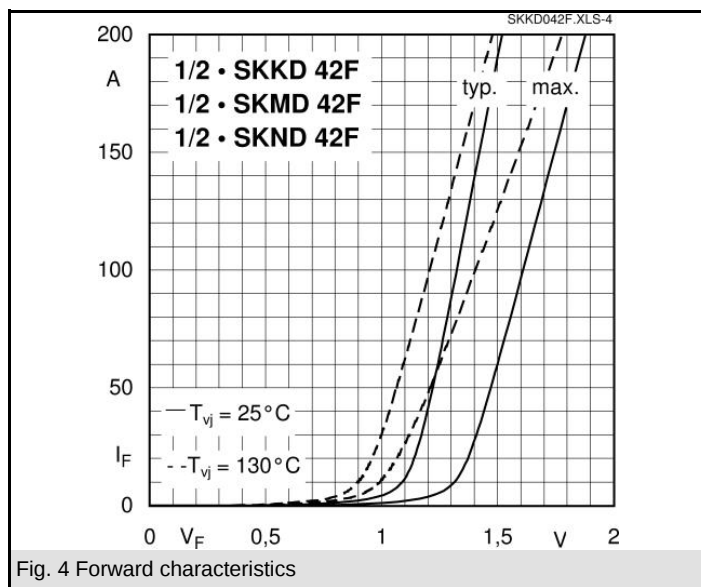
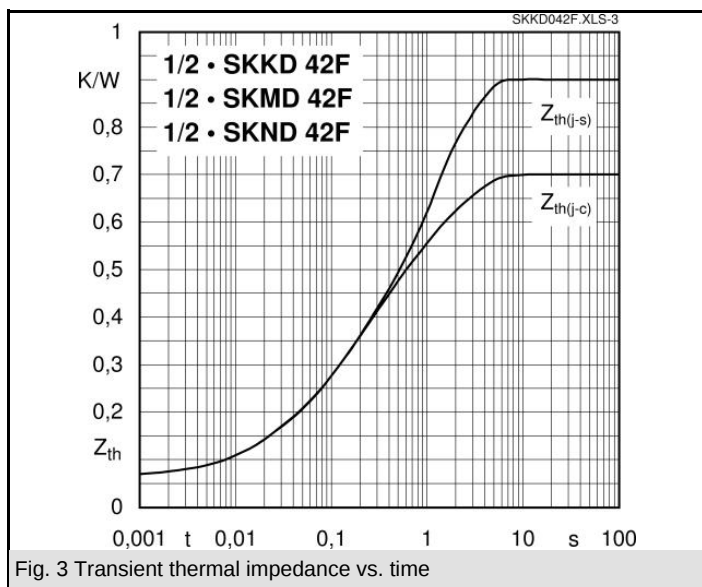
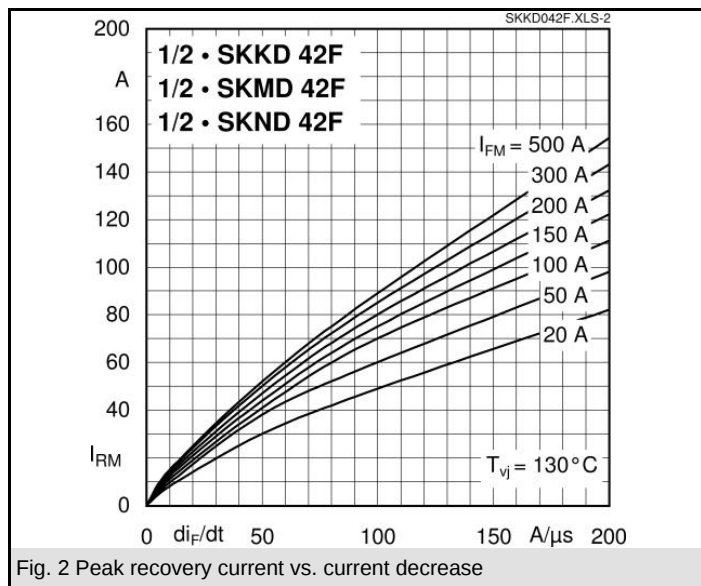
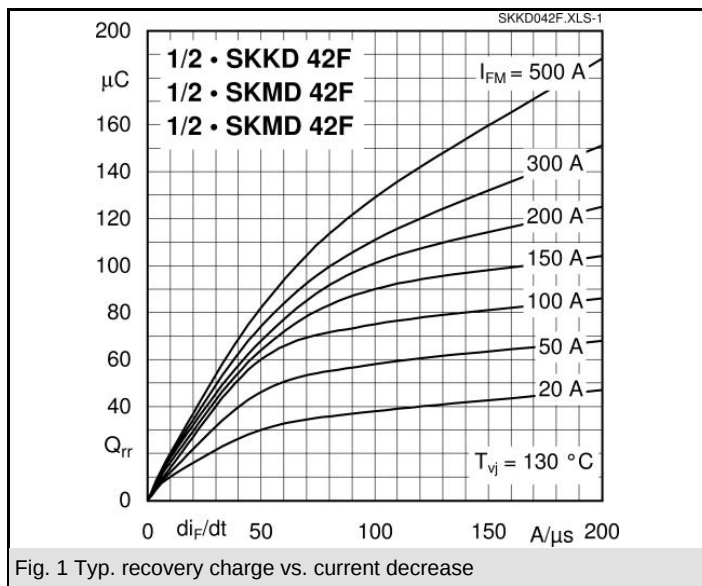


SKKD

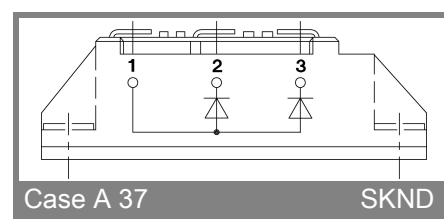
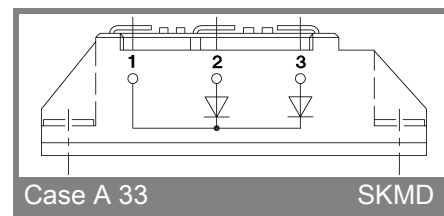
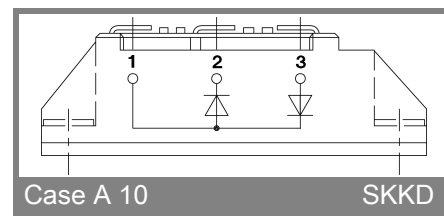
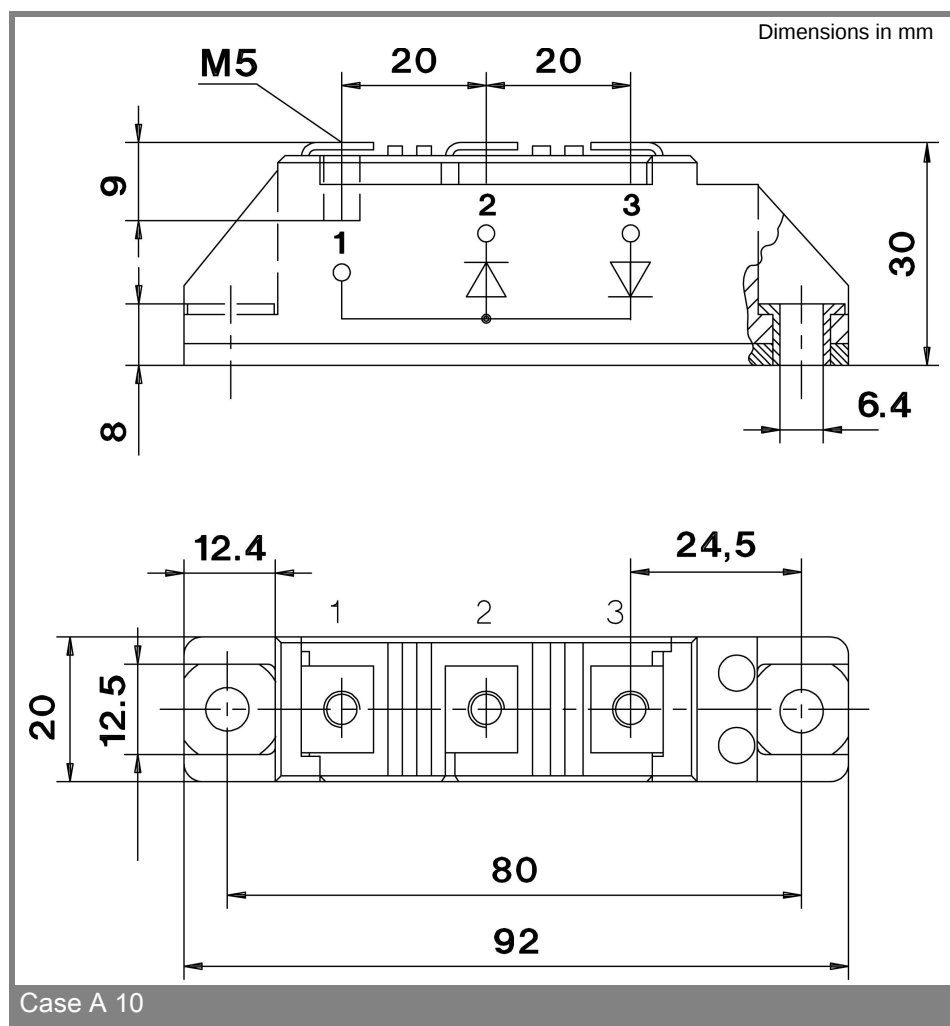
SKMD

SKND

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